



High forward current capability
Low forward losses
Low thermal resistance
High load cycle capability

**Rectifier Diode
For Welding**
Type D053-7100-4-N

Average forward current	I _{FAV}	7402 A
Repetitive peak reverse voltage	V _{RRM}	200 ÷ 400 V
V _{RRM} , V	200	400
Voltage code	2	4
T _j , °C		- 60 ÷ 170

MAXIMUM ALLOWABLE RATINGS

Symbols and parameters		Units	Values	Test conditions	
ON-STATE					
I _{FAV}	Average forward current	A	7100 7402	T _c = 89,8 °C; Double side cooled; T _c = 85 °C; Double side cooled; 180° half-sine wave; 50 Hz	
I _{FRMS}	RMS forward current	A	11147	T _c = 89,8 °C; Double side cooled; 180° half-sine wave; 50 Hz	
I _{FSM}	Surge forward current	kA	55.0 63.0	T _j =T _{j max} T _j =25 °C	180° half-sine wave; 50 Hz (t _p =10 ms); single pulse; V _R =0 V;
			58.0 67.0	T _j =T _{j max} T _j =25 °C	180° half-sine wave; 60 Hz (t _p =8.3 ms); single pulse; V _R =0 V;
I ² t	Safety factor	A ² s·10 ³	15125 19845	T _j =T _{j max} T _j =25 °C	180° half-sine wave; 50 Hz (t _p =10 ms); single pulse; V _R =0 V;
			13960 18625	T _j =T _{j max} T _j =25 °C	180° half-sine wave; 60 Hz (t _p =8.3 ms); single pulse; V _R =0 V;
BLOCKING					
V _{RRM}	Repetitive peak reverse voltages	V	200 ÷ 400	T _{j min} < T _j <T _{j max} ; 180° half-sine wave; 50 Hz;	
V _{RSM}	Non-repetitive peak reverse voltages	V	300 ÷ 500	T _{j min} < T _j <T _{j max} ; 180° half-sine wave; 50 Hz;single pulse;	
V _R	Reverse continuous voltages	V	0.75·V _{RRM}	T _j =T _{j max} ;	
THERMAL					
T _{stg}	Storage temperature	°C	- 60 ÷ 170		
T _j	Operating junction temperature	°C	- 60 ÷ 170		
MECHANICAL					
F	Mounting force	kN	30.0 ÷ 36.0		
a	Acceleration	m/s ²	50 100	Device unclamped Device clamped	

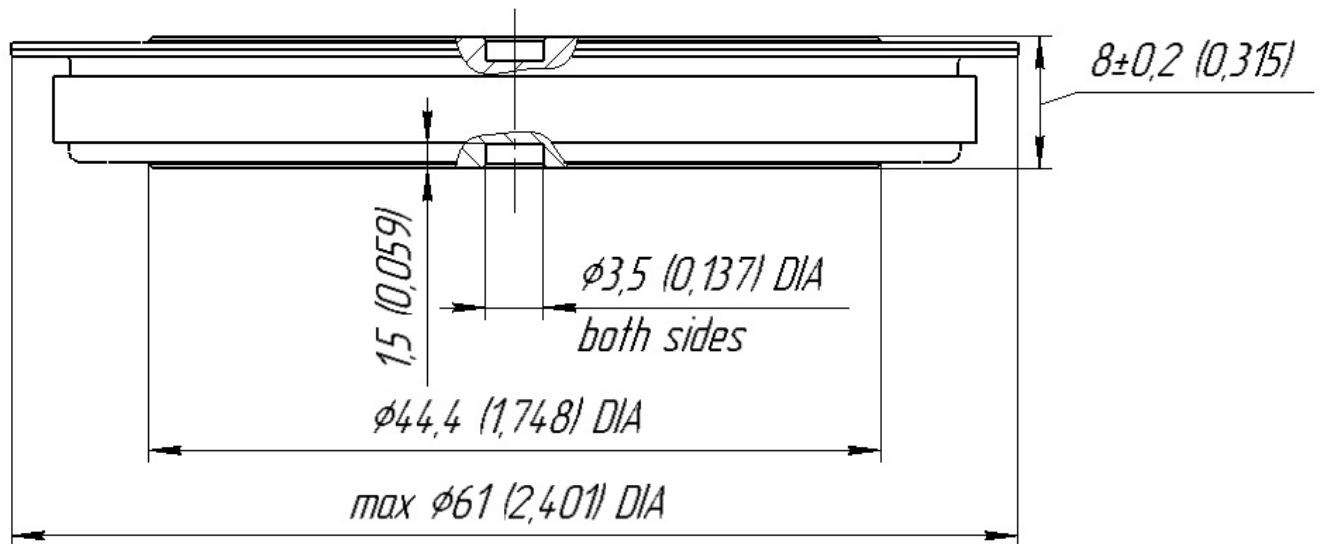
CHARACTERISTICS

Symbols and parameters		Units	Values	Conditions
ON-STATE				
V _{FM}	Peak forward voltage, max	V	1.05 0.89	T _j =25 °C; I _{FM} = 5000 A T _j =T _j max; I _{FM} = 5000 A
V _{F(TO)}	Forward threshold voltage, max	V	0.750	T _j =T _j max;
r _T	Forward slope resistance, max	mΩ	0.029	5000 A < I _T < 14000 A
BLOCKING				
I _{RRM}	Repetitive peak reverse current, max	mA	50	T _j =T _j max; V _R =V _{RRM}
SWITCHING				
Q _{rr}	Total recovered charge, max	μC	950	T _j =T _j max; I _{FM} =1000 A; dI _{FM} /dt=-30 A/μs
			620	T _j =T _j max; I _{FM} =1000 A; dI _{FM} /dt=-10 A/μs
THERMAL				
R _{thjc}	Thermal resistance, junction to case, max	°C/W	0.0090	Double side cooled
R _{thjc-A}			0.0210	Direct current Anode side cooled
R _{thjc-K}			0.0160	Cathode side cooled
R _{thck}	Thermal resistance, case to heatsink, max	°C/W	0.0050	Direct current
MECHANICAL				
w	Weight, typ	g	140	
D _s	Surface creepage distance	mm (inch)	7.3 (0.287)	
D _a	Air strike distance	mm (inch)	4.0 (0.157)	

PART NUMBERING GUIDE

D	053	7100	4	N
1	2	3	4	

1. Design version
2. Average forward current, A
3. Voltage code
4. Ambient conditions: N – normal

OVERALL DIMENSIONS**Package type: D.Q1**

All dimensions in millimeters (inches)

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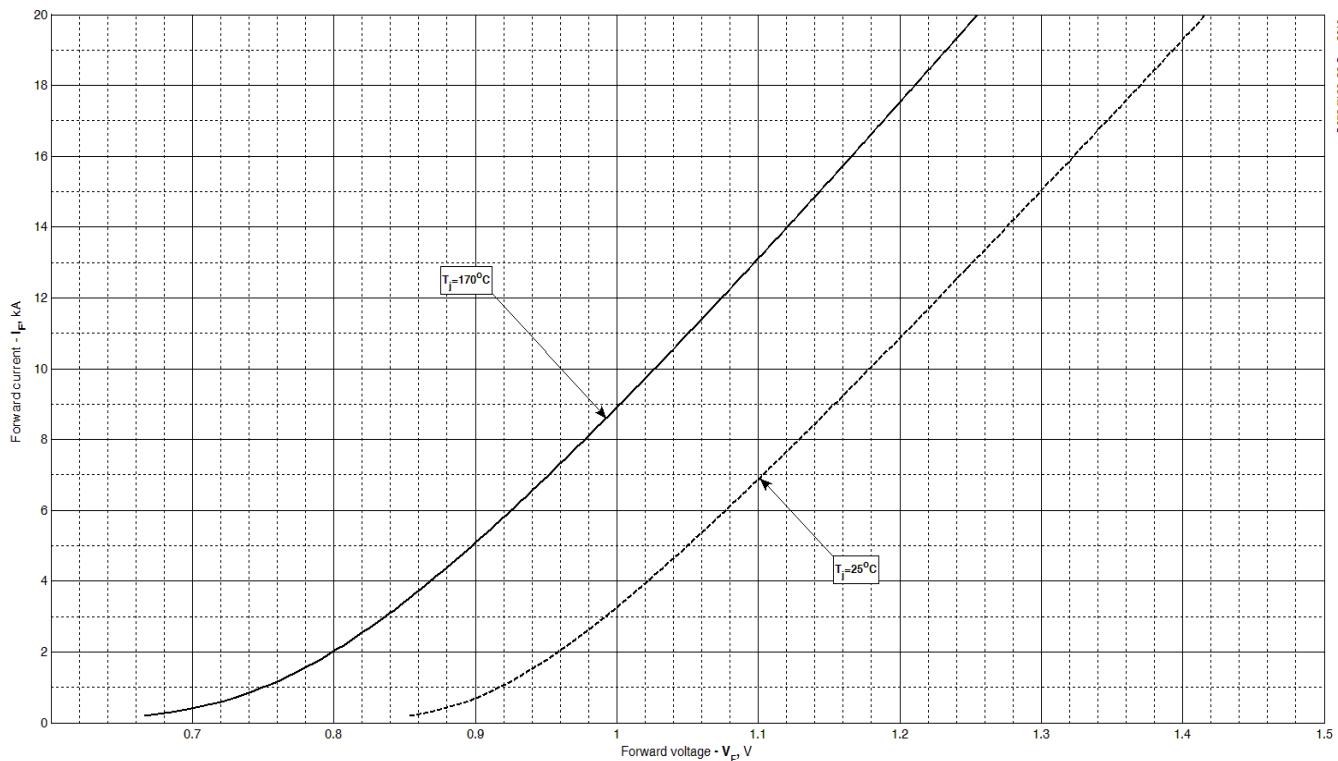


Fig 1 – Forward characteristics of Limit device

Analytical function for Forward characteristic:

$$V_F = A + B \cdot i_F + C \cdot \ln(i_F + 1) + D \cdot \sqrt{i_F}$$

	Coefficients for max curves	
	$T_j = 25^\circ\text{C}$	$T_j = T_{j\max}$
A	0.869879	0.692620
B	0.022542	0.021003
C	0.074643	0.110962
D	-0.029819	-0.044329

Forward characteristic model (see Fig. 1).

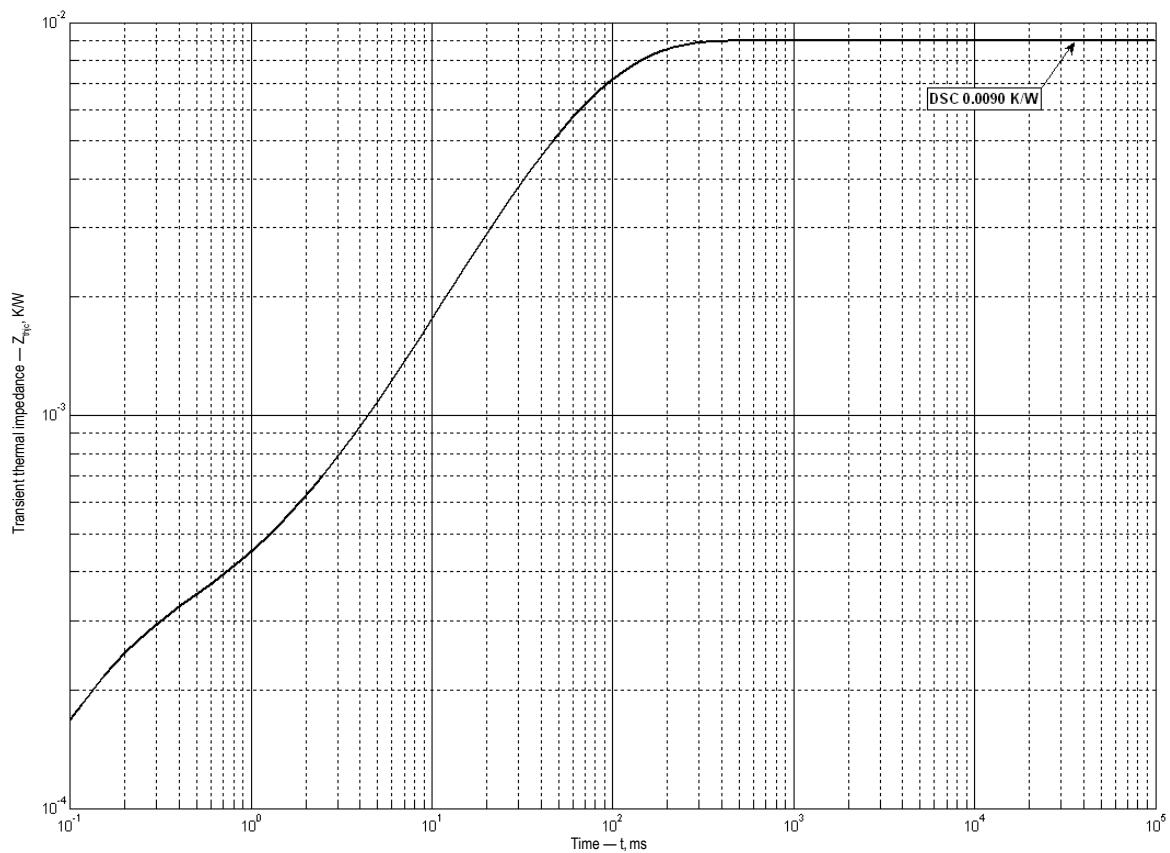


Fig 2 – Transient thermal impedance

Analytical function for Transient thermal impedance junction to case Z_{thjc} for DC:

$$Z_{thjc} = \sum_{i=1}^n R_i \left(1 - e^{-\frac{t}{\tau_i}} \right)$$

Where $i = 1$ to n , n is the number of terms in the series.

t = Duration of heating pulse in seconds.

Z_{thjc} = Thermal resistance at time t.

R_i = Amplitude of p_{th} term.

τ_i = Time constant of r_{th} term.

DC Double side cooled

i	1	2	3	4	5	6
R_i , K/W	0.001448	0.006594	0.0006431	0.00004826	0.00004138	0.0002254
τ_i , s	0.08908	0.06263	0.01451	0.00151	0.0003338	0.0001058

Transient thermal impedance junction to case Z_{thjc} model (see Fig. 2)

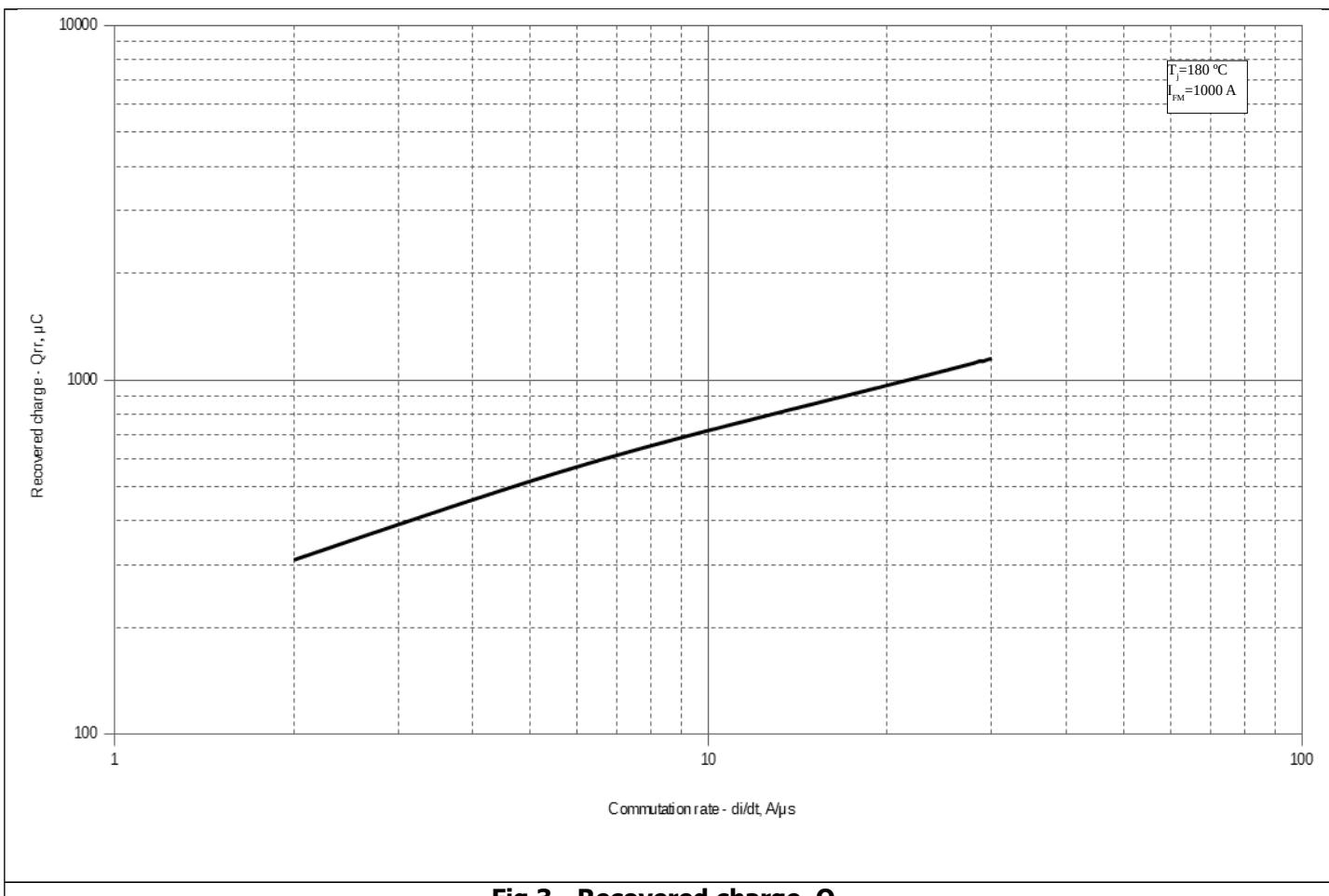


Fig 3 - Recovered charge, Q_{rr}

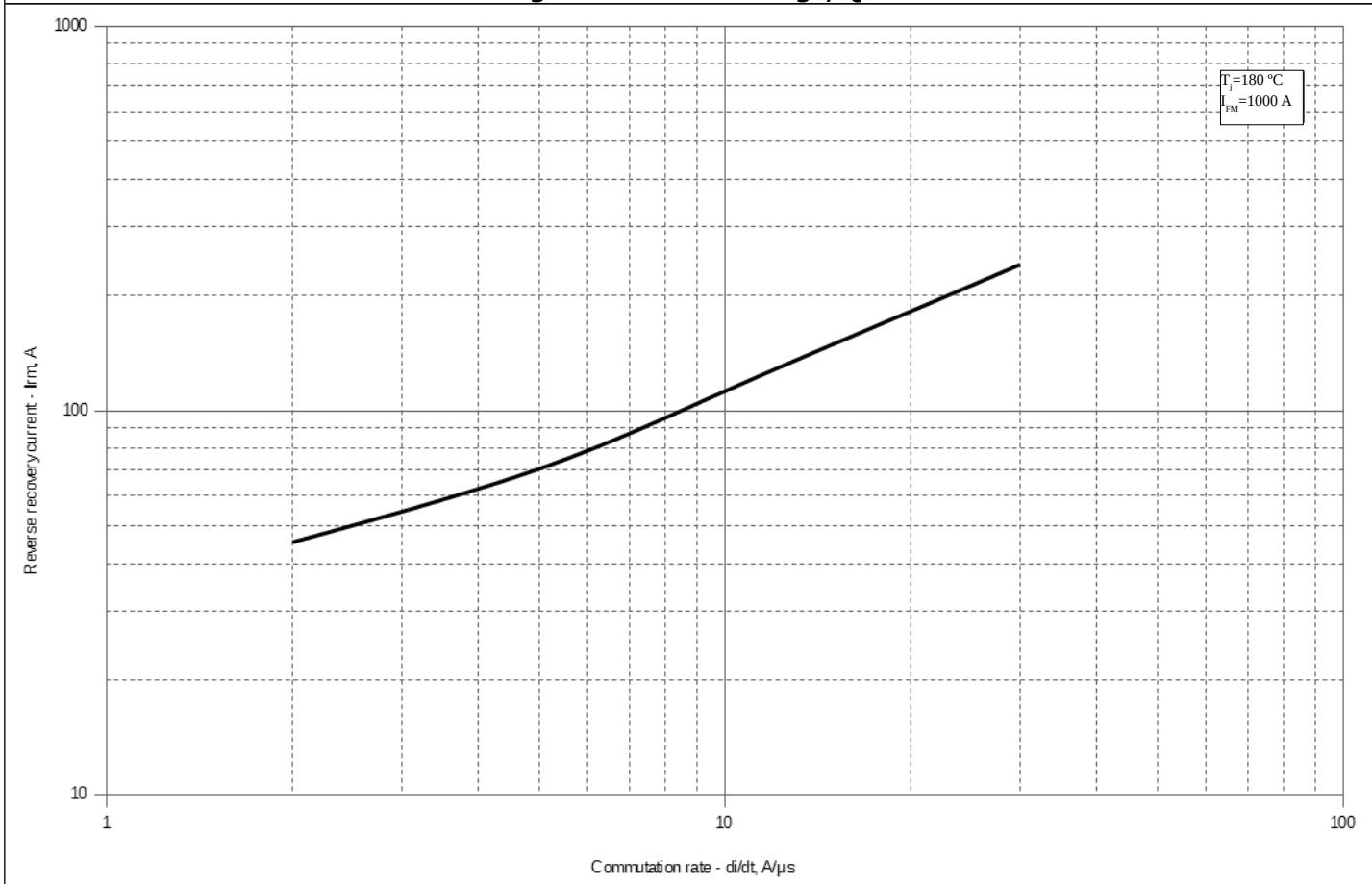


Fig 4 – Peak reverse recovery current, I_{rm}

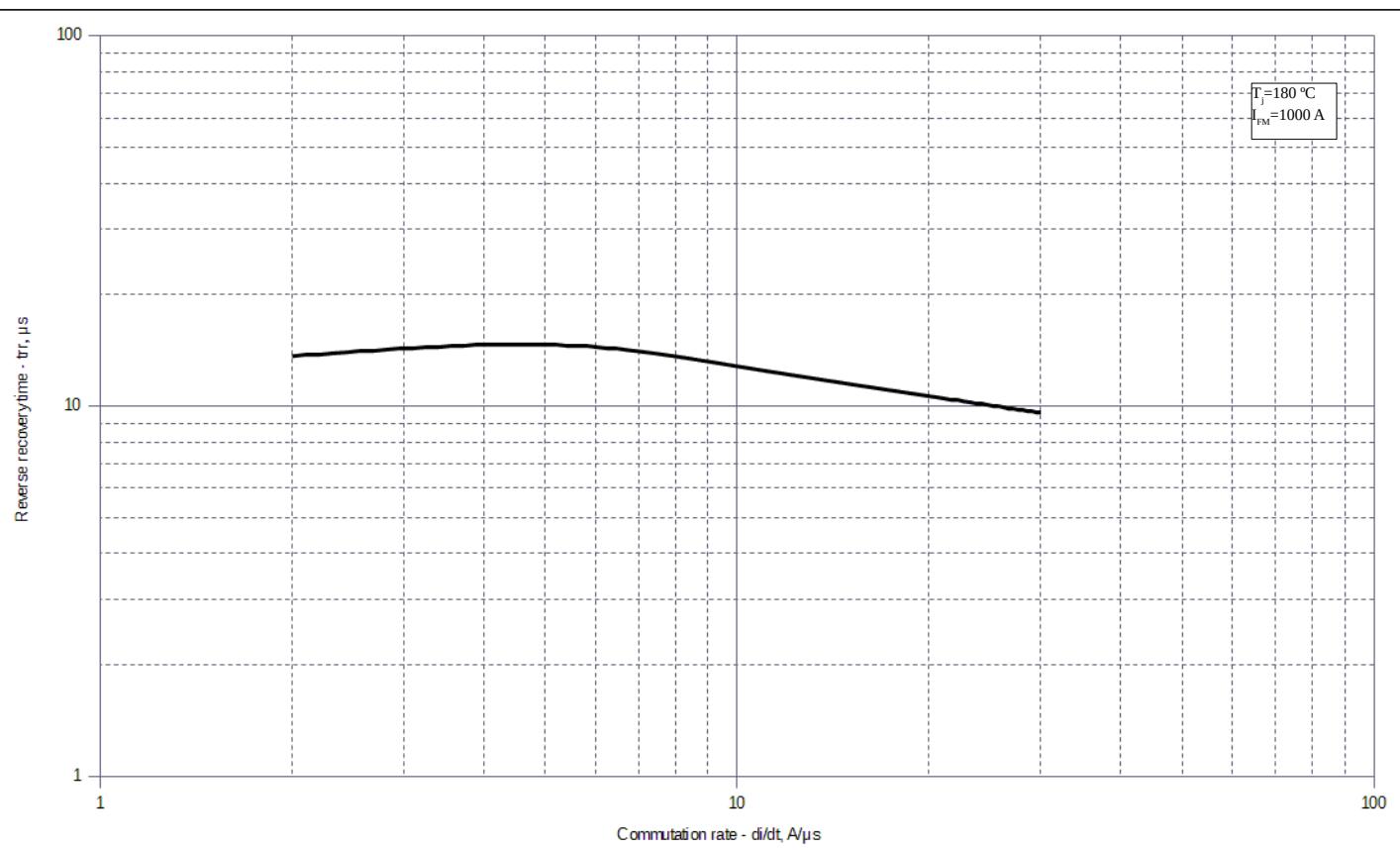


Fig 5 – Maximum recovery time, t_{rr} (linear)

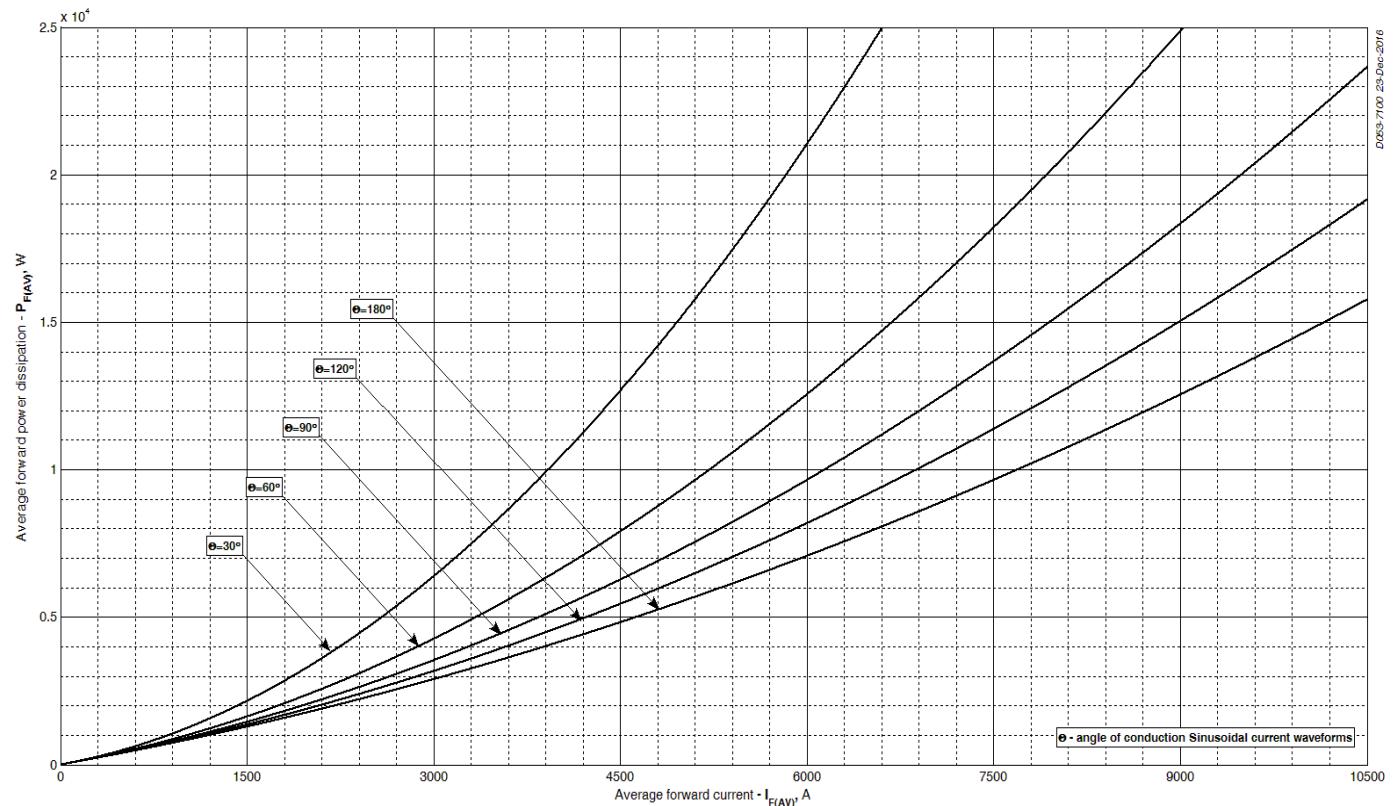


Fig 6 – Mean forward power dissipation P_{FAV} vs. Mean forward current I_{FAV} for sinusoidal current waveforms at different conduction angles (f=50Hz, DSC)

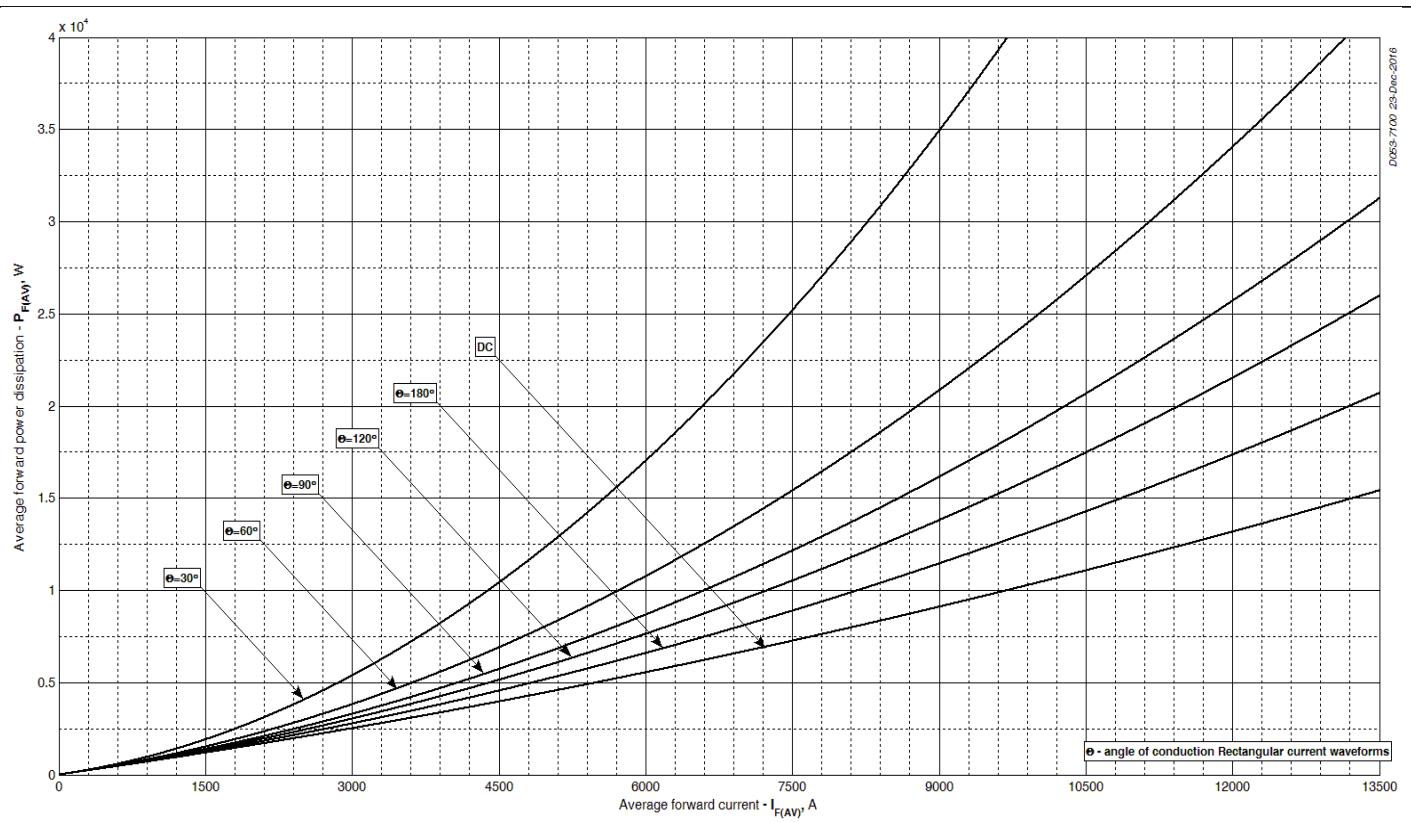


Fig 7 – Mean forward power dissipation P_{FAV} vs. Mean forward current I_{FAV} for rectangular current waveforms at different conduction angles and for DC (f=50Hz, DSC)

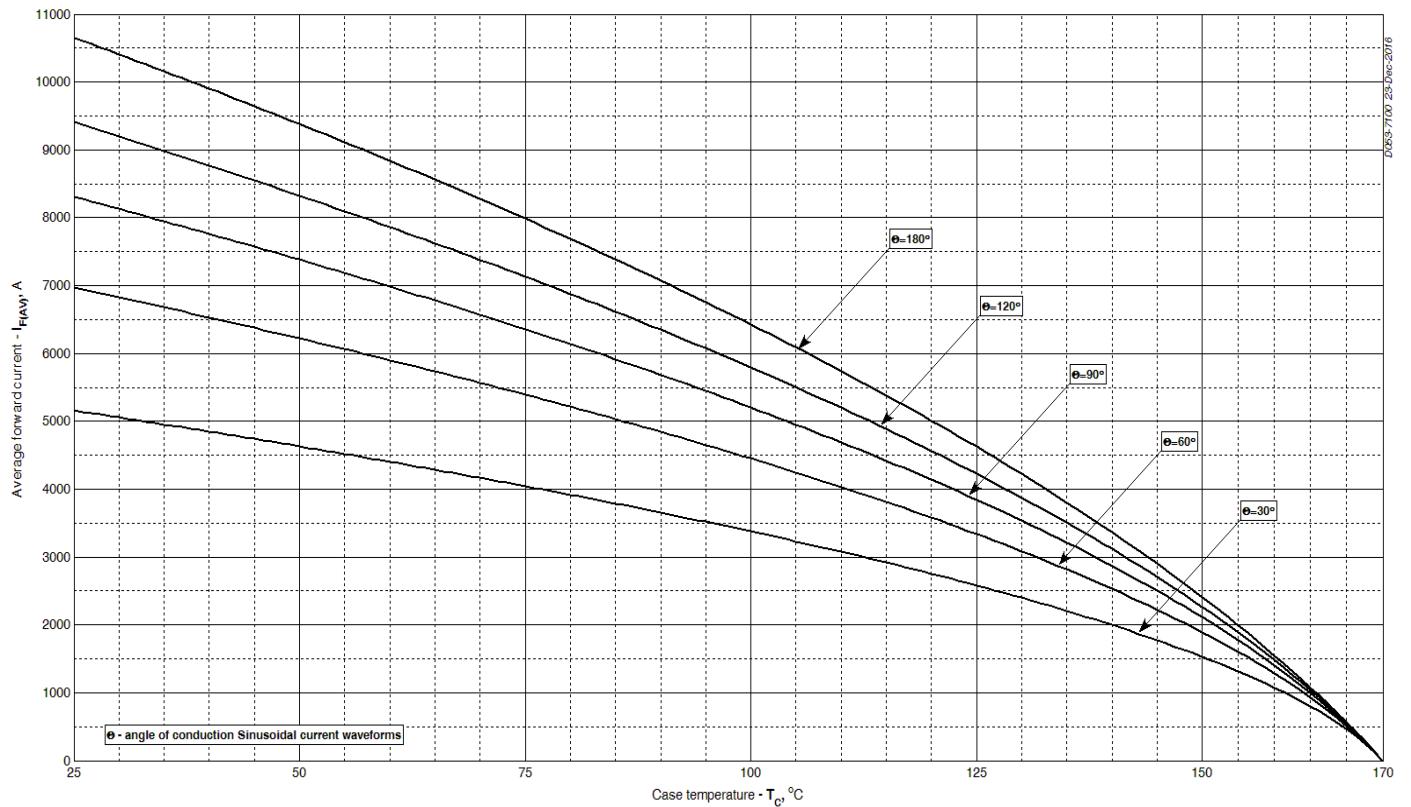


Fig 8 - Mean forward current I_{FAV} vs. Case temperature T_c for sinusoidal current waveforms at different conduction angles (f=50Hz, DSC)

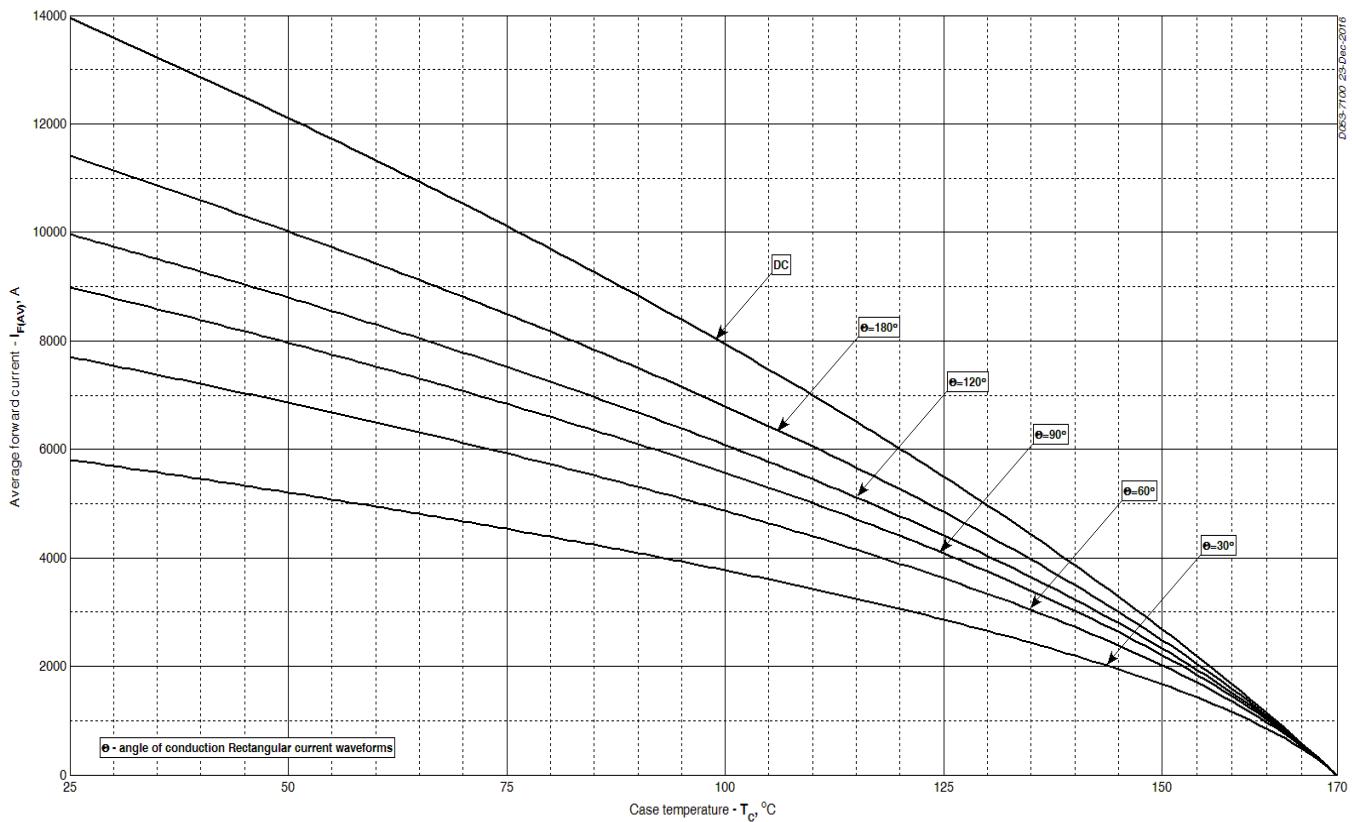


Fig 9 – Mean forward current I_{FAV} vs. Case temperature T_c for rectangular current waveforms at different conduction angles and for DC (f=50Hz, DSC)

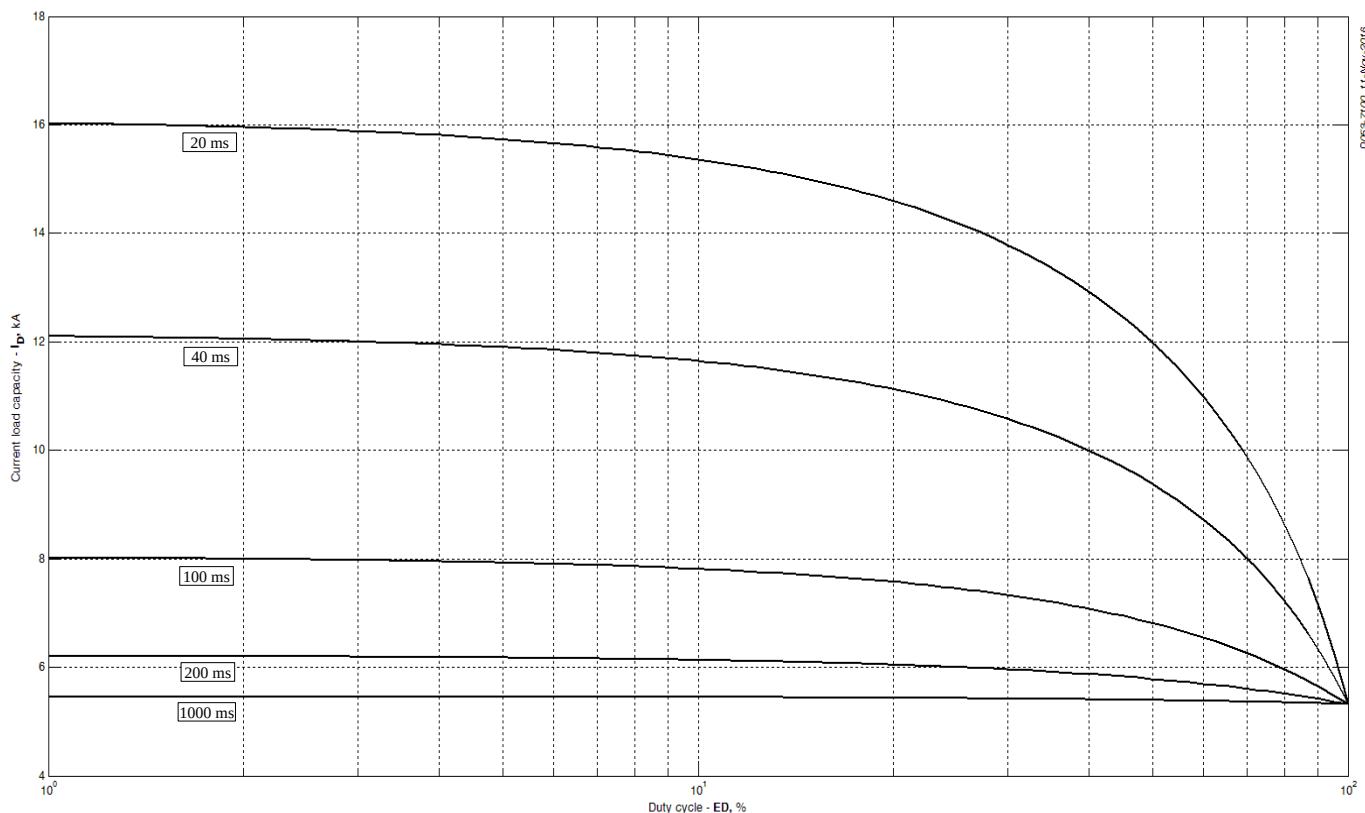


Fig 10 – Current load capability (f=1000 Hz, square wave, $T_c = 40$ °C)

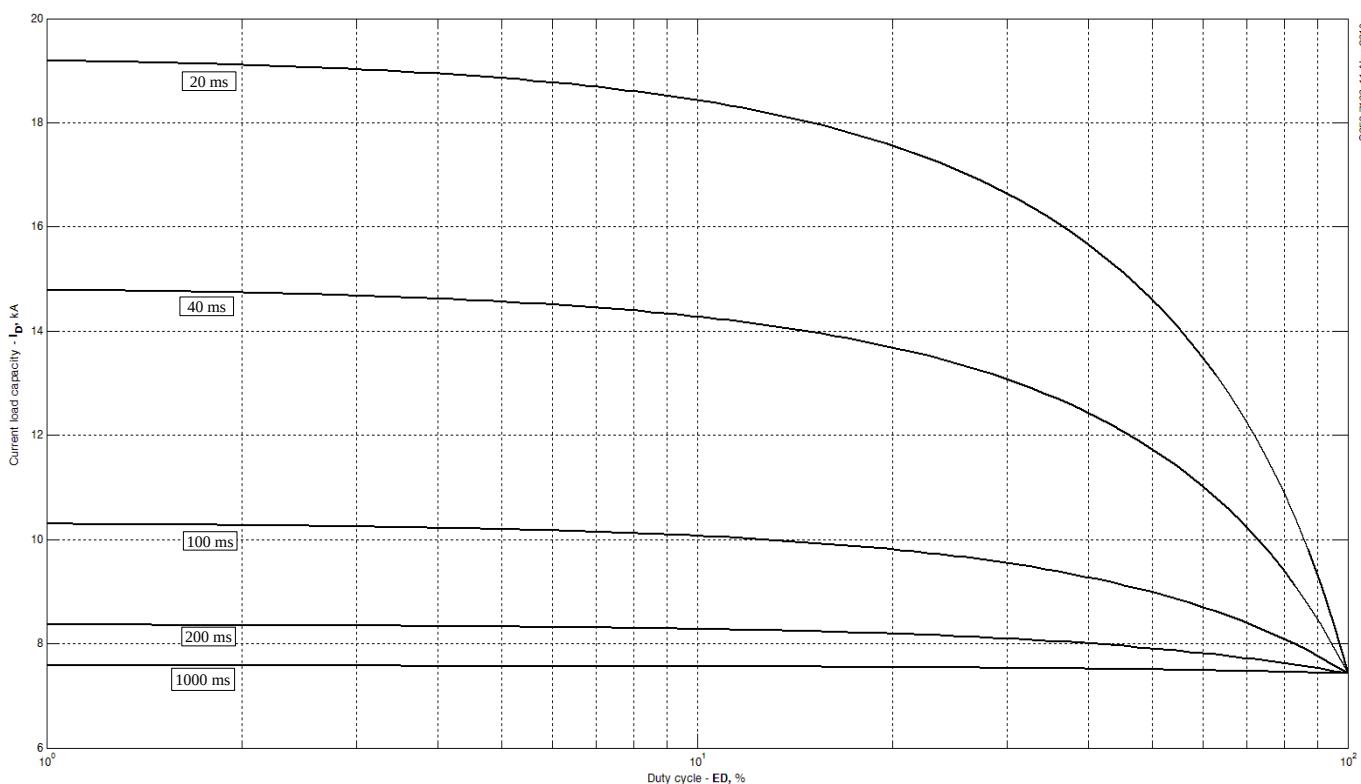


Fig 11 – Current load capability (f=1000 Hz, square wave, $T_c = 60^\circ\text{C}$)

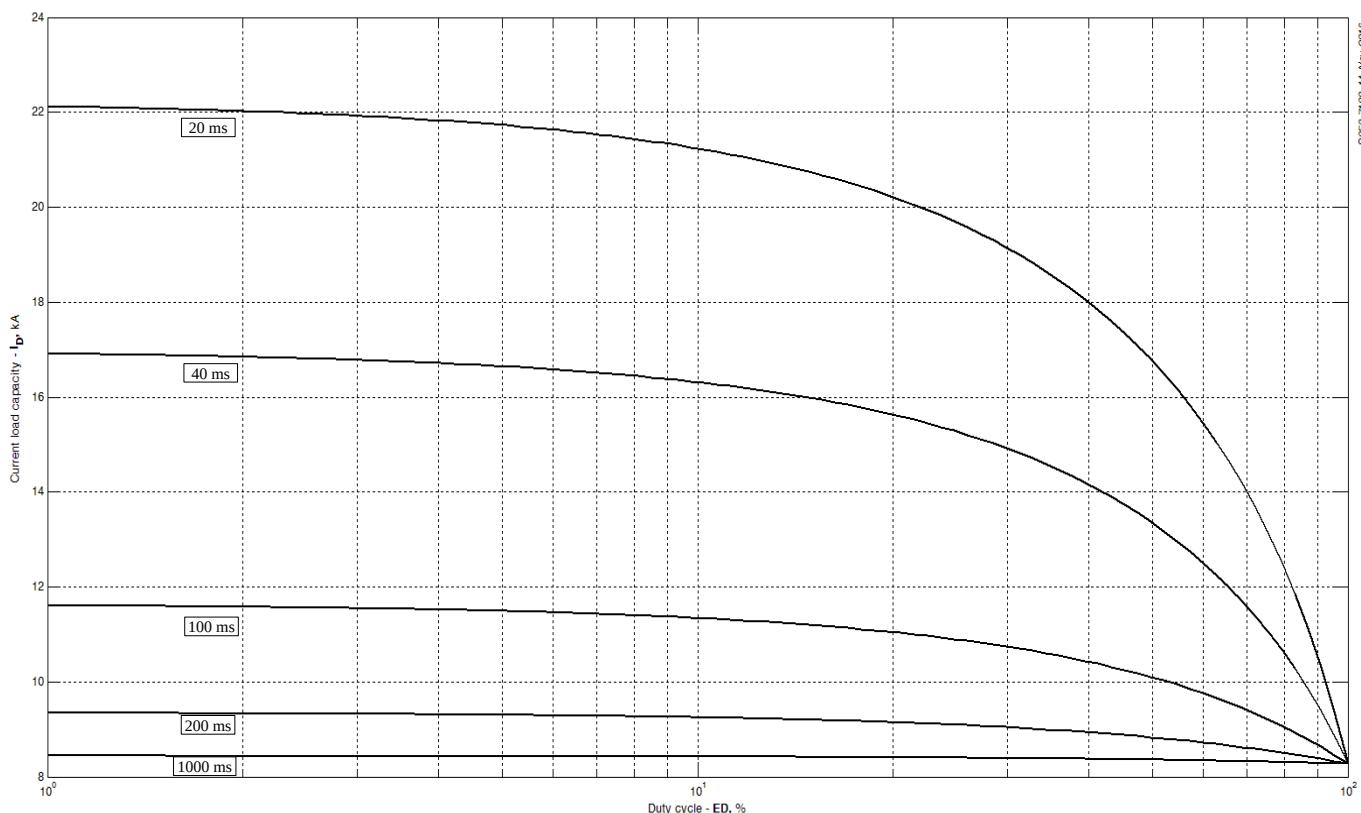


Fig 12 – Current load capability (f=1000 Hz, square wave, $T_c = 70^\circ\text{C}$)

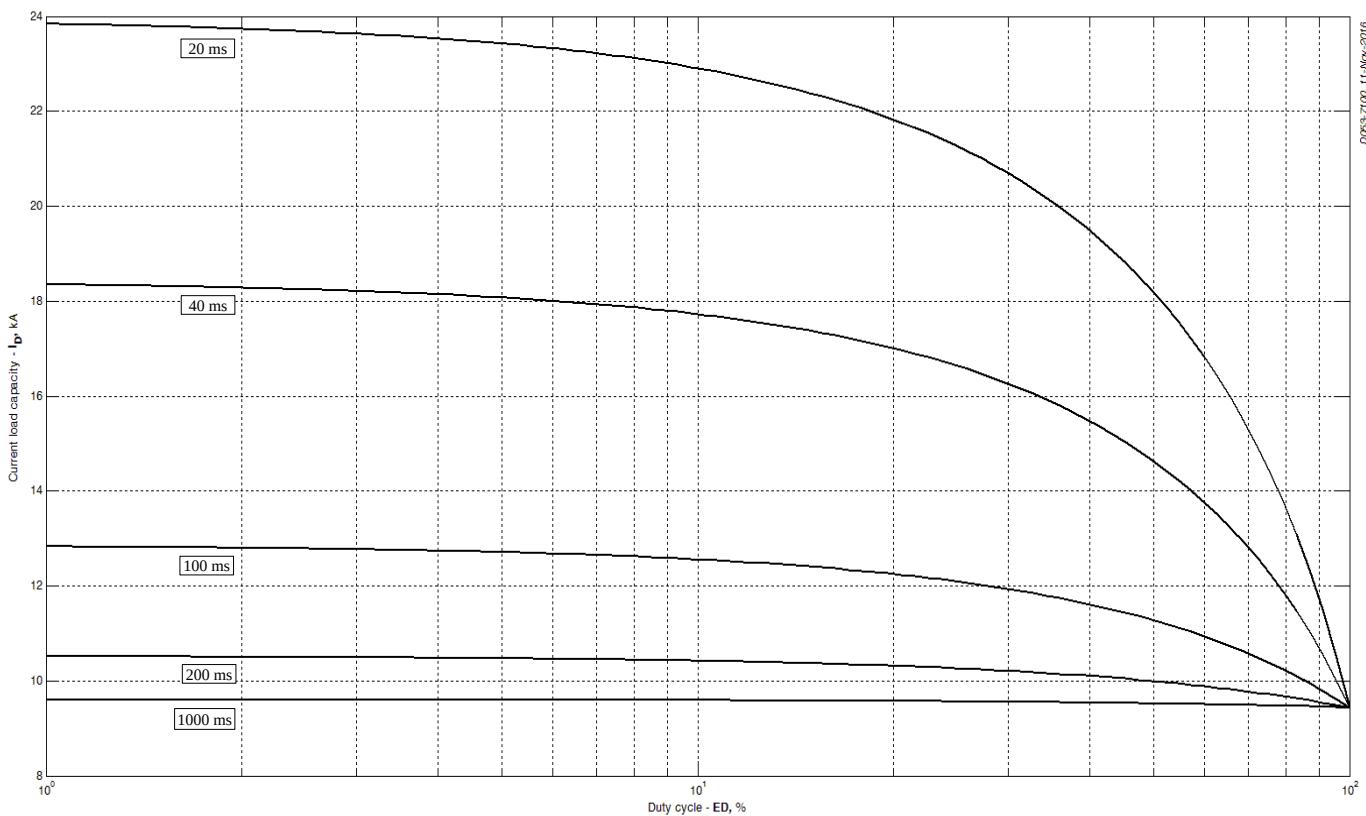


Fig 13 – Current load capability (f=1000 Hz, square wave, $T_c = 80^\circ\text{C}$)

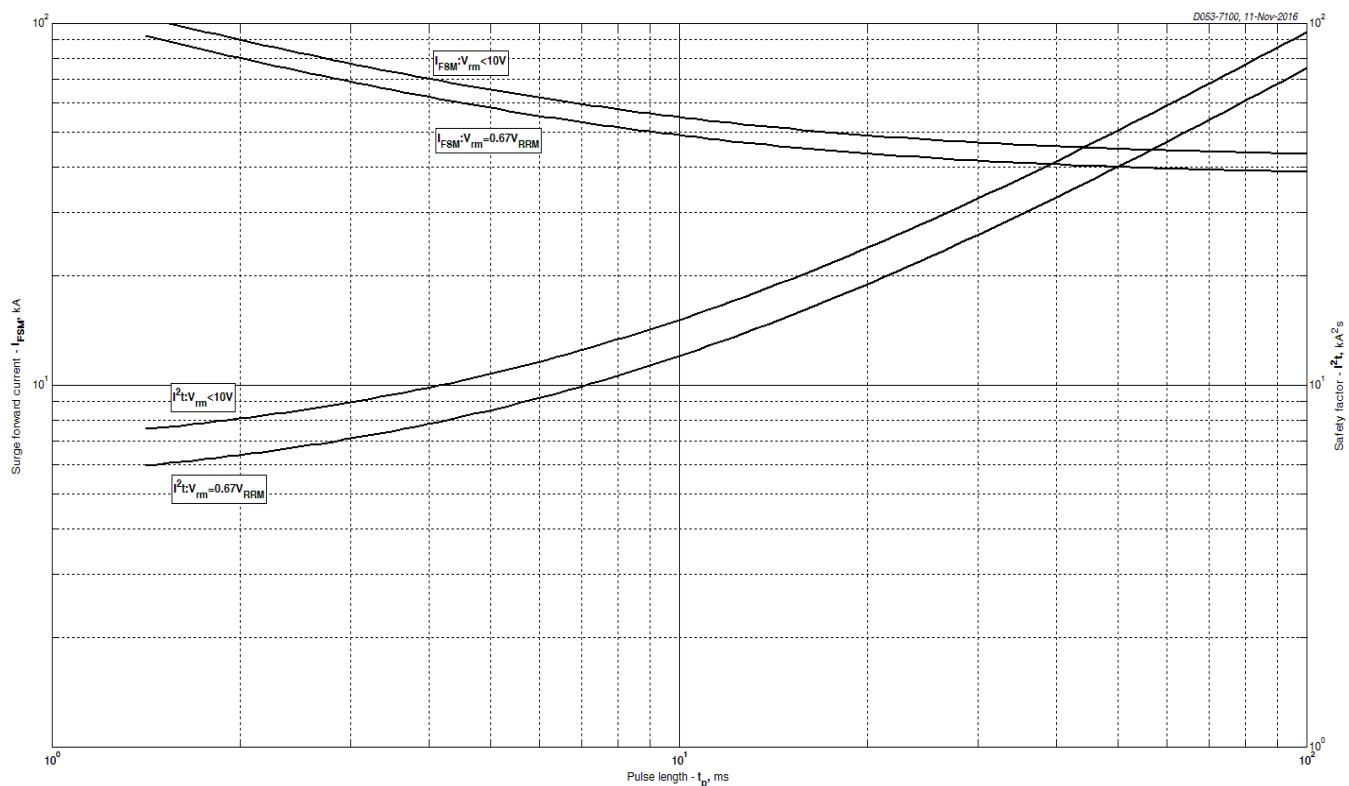


Fig 14 – Maximum surge and I^2t ratings

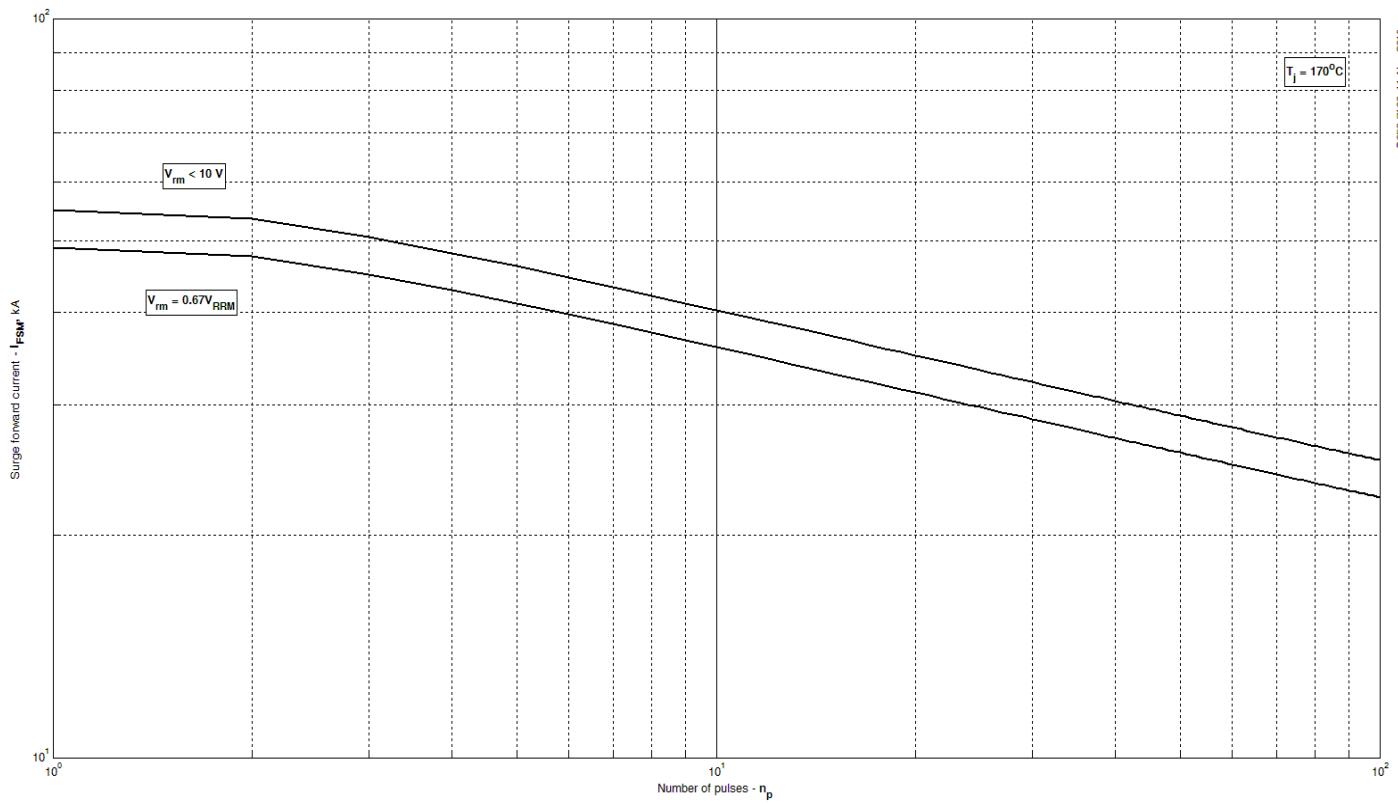
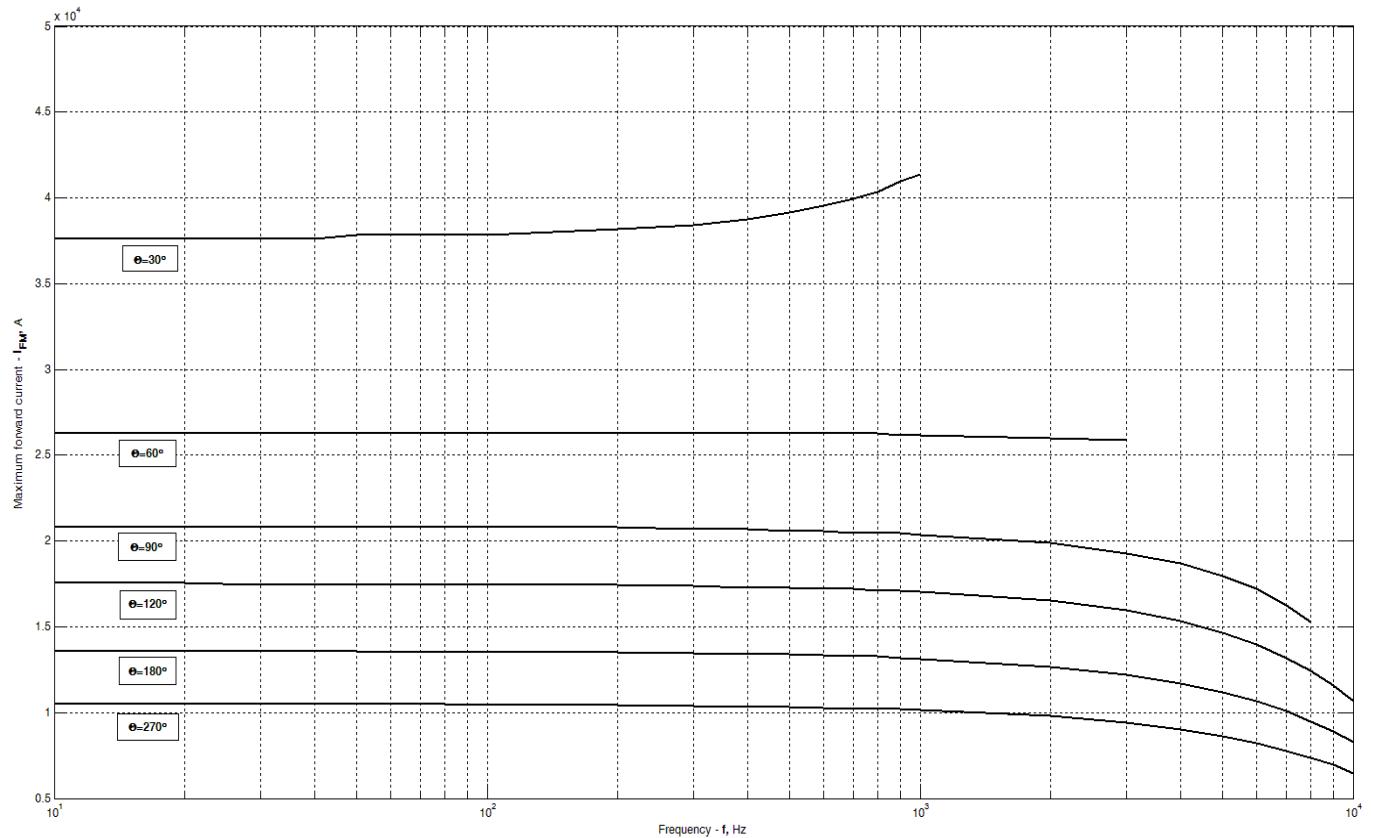
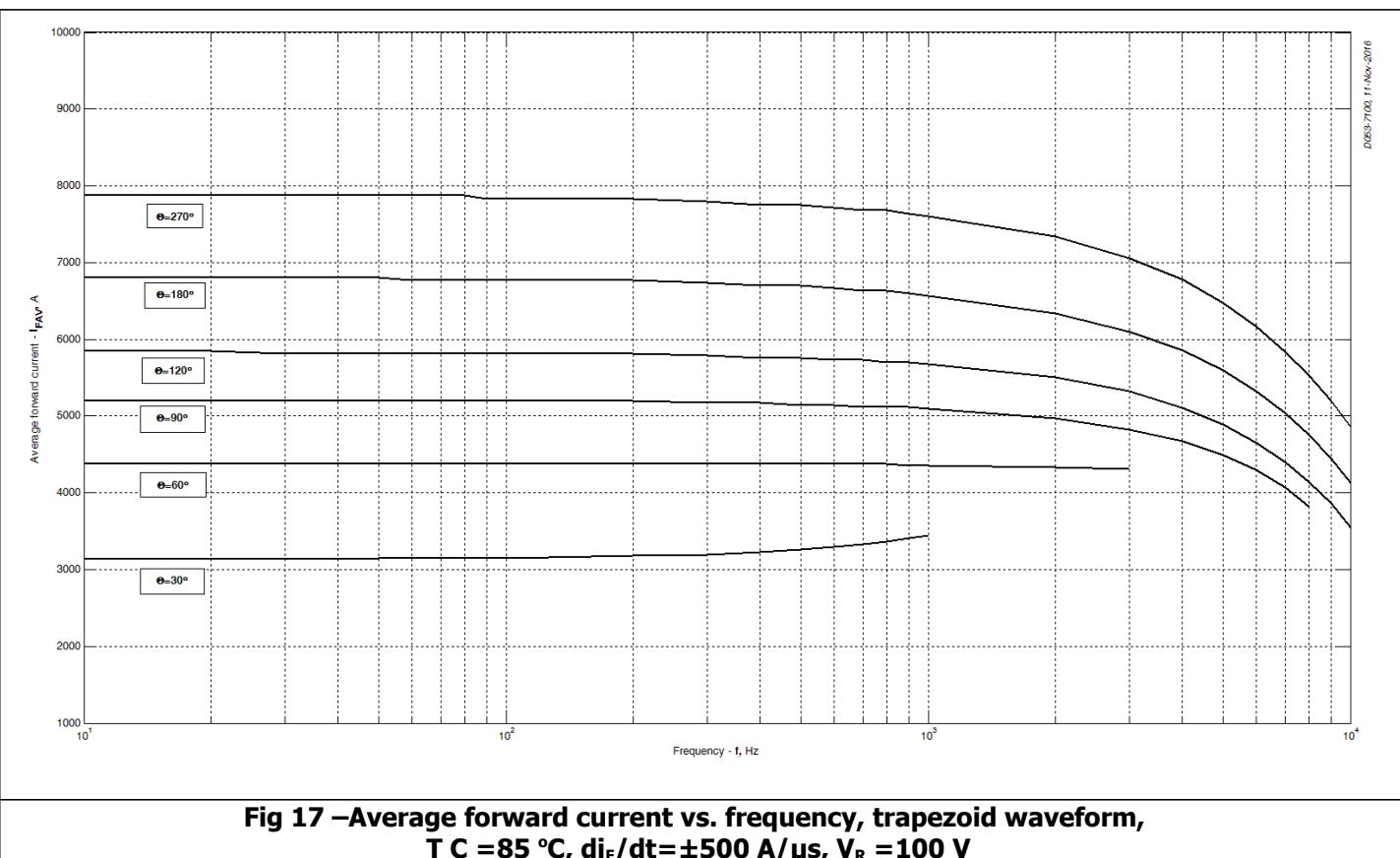


Fig 15 – Maximum surge ratings



**Fig 16 –Maximum forward current vs. frequency, trapezoid waveform,
 $T_C=85^\circ\text{C}$, $di_F/dt=\pm 500 \text{ A}/\mu\text{s}$, $V_R=100 \text{ V}$**



**Fig 17 –Average forward current vs. frequency, trapezoid waveform,
T C =85 °C, $di_F/dt=\pm 500$ A/ μ s, V_R =100 V**